

**AE-X36DXXX-X Series
PECL/LVPECL UHF VCXO**

Rev. R

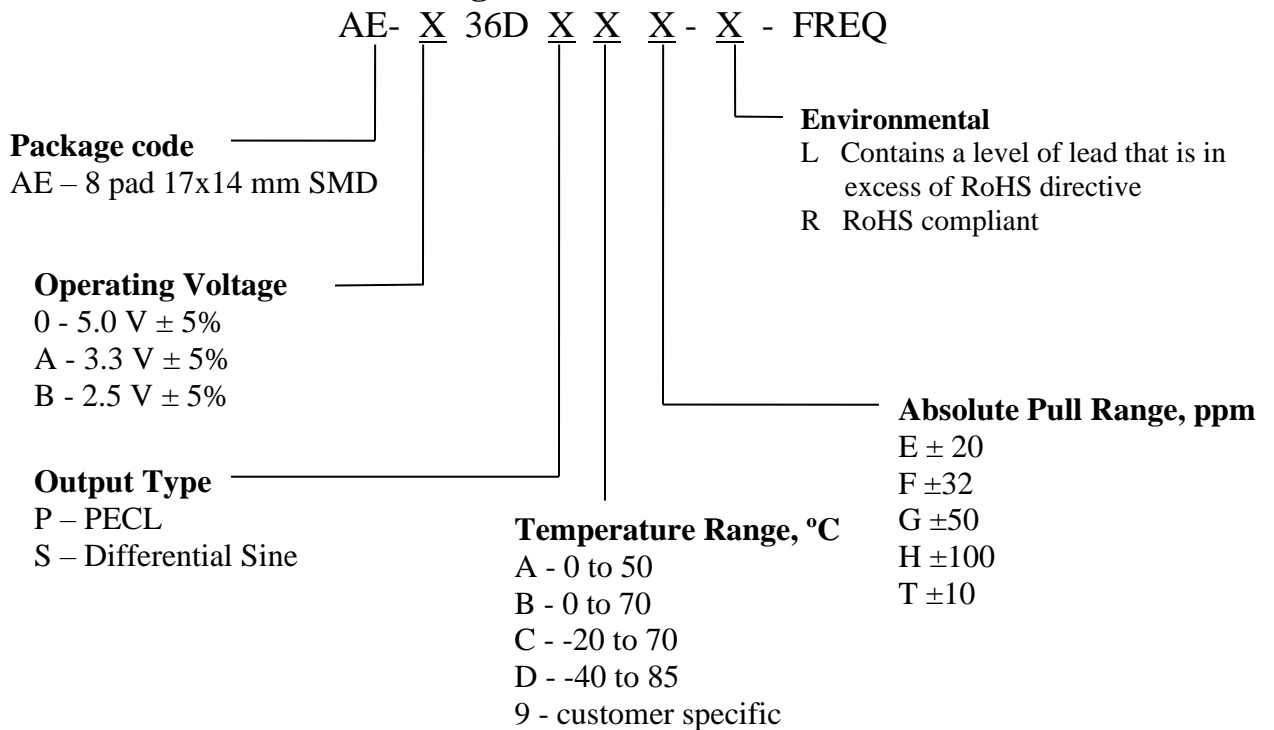
Description

The **AE-XXXX Series** of voltage-controlled crystal oscillators (VCXO) provides ultra-high frequency with PECL/LVPECL or differential Sine-Wave complementary outputs. The device is based on low noise analog harmonic frequency multiplication, providing exceptionally low Phase Noise and Jitter. It's packaged in a miniature, FR-4 based 17x14 mm SMD package.

Applications and Features

- Fiber Channel; 10 GbE; Infiniband; Network Processors; SONET/SDH
- High Reliability – NEL HALT/HASS qualified for crystal oscillator start-up conditions
- Extremely Low Phase Noise and Jitter
- Frequency Range to 2,000 MHz
- Absolute Pull Range (APR) to $\pm 1,000$ ppm
- SONET ± 20 ppm overall free-run stability available
- High Shock Resistance, to 1000g
- COTS/Dual use

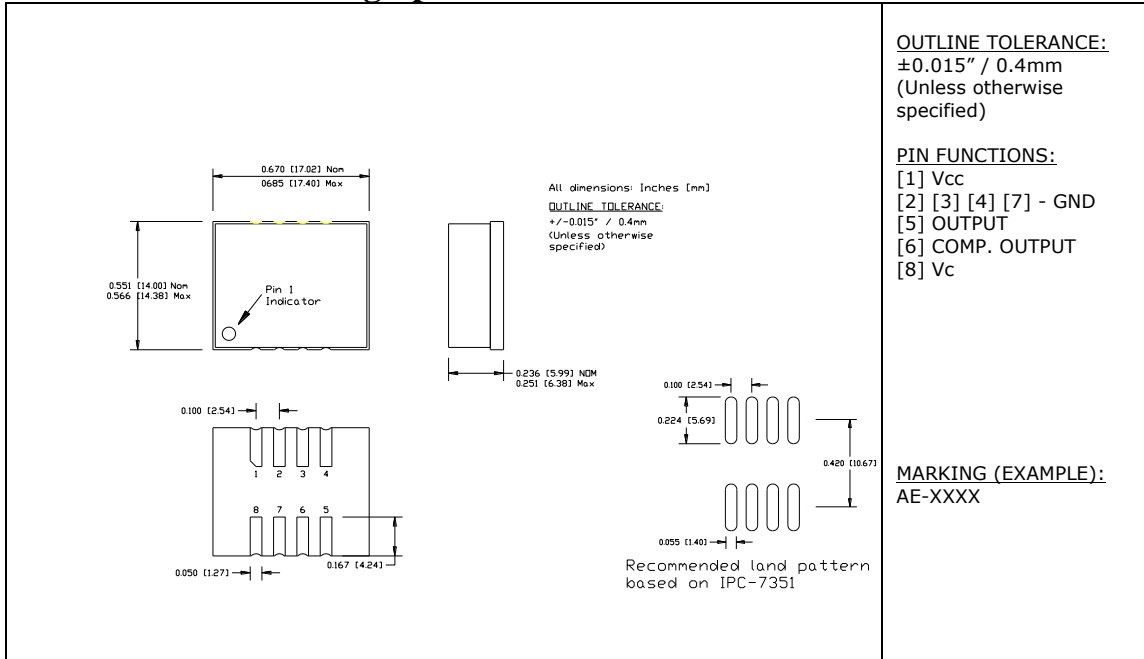
Creating a Part Number



AE-X36DXXX-X Series

Rev. R

Drawing Specification



Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Operating Temperature Range	T _o	-40 to +85	°C
Storage Temperature Range	T _{st}	-50 to +90	°C
Supply Voltage	V _{cc}	-0.5 to 5.5	V
Control Voltage	V _c	-0.5 to 5.5	V



AE-X36DXXX-X Series

Rev. R

Electrical Parameters

Parameter*		Symb	Conditions, Note	MIN	TYP	MAX	Unit
Nominal Frequency		Fo	See Note below	250		2,000	MHz
Supply Voltage		Vcc	Code 0 Code A Code B	4.75 3.135 2.375	5.0 3.3 2.5	5.25 3.465 2.625	V
Supply current		Icc	Code 0 Code A Code B			220 195 160	mA
Output Logic Type					LVPECL Sine		
Load			Output to Vcc-2V, or Thevenin Equivalent, PECL Sine – internally AC coupled		50		Ohm
Output Levels		Voh Vol	PECL Sine	Vcc-1.025		Vcc-1.620	V
Duty Cycle (Symmetry), PECL			At 50% of output voltage swing	45/55	50/50	55/45	%
Rise/Fall Time, PECL		Tr/Tf	20 to 80, 80 to 20%		0.25	0.3	ns
Jitter	Integrated	J	Integrated from Phase Noise, 12 KHz to 20 MHz RMS		0.1	0.2	ps
			100Hz to 80KHz,RMS			1.0	ns
			50 KHz to 80 MHz		0.3		ps
	Wavecrest characterized		Random period,		2.5		ps
			Accumul., pk-to-pk		25		ps
			Determine.		1		ps
Phase Noise		£(Δf)	1,500 MHz, APR 50 ppm or less	@ 10 Hz @ 100 Hz @ 1 KHz @ 10KHz @ 100KHz @ >1MHz	-50 -80 -115 -130 -130 -135	-45 -75 -110 -125 -125 -130	dBc/Hz
Sub-harmonics			At 1,500 MHz		-50	-46	dBc
Frequency Stability, usually not specified – unless necessary, APR is specified to incorporate stability		ΔF/F	Overall, including temperature, aging 10 years, shock and vibration @ Vc=Vcc/2; APR 50 ppm, or less	±20	±30		ppm
Control Voltage Range		Vc		0V		Vcc	V
Setability		Vcs	Vc to set the F at Fo; T, Vcc, load – nominal, as shipped	0.4 Vcc	0.5 Vcc	0.6 Vcc	V
Absolute Pull Range		APR	Over all conditions, see part # creation	10,20, 32, 50, 100			ppm
Input impedance		Zin	@ Fmod < 100 KHz	50			KOhm
Modulation Bandwidth			At Vc = Vcc/2, -3dB	20			KHz

*Note: All parameters, unless noted otherwise are specified for nominal conditions, i.e.: ambient temperature is 25°C, Vcc – nominal.



AE-X36DXXX-X Series

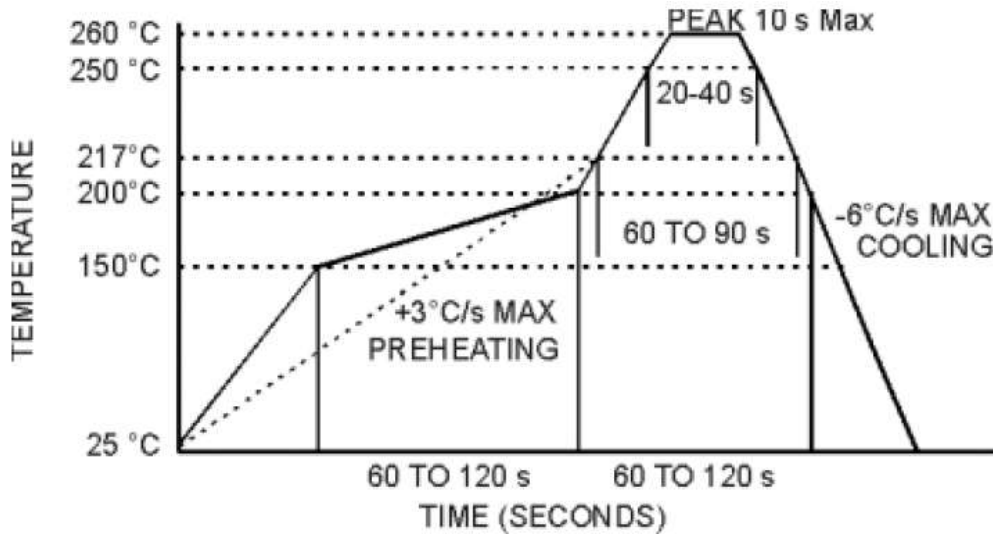
Rev. R

Environmental and Mechanical Characteristics

Operating temp. range	see part # table
Mechanical Shock	Per MIL-STD-202, Method 213, Cond. A
Thermal Shock	Per MIL-STD-883, Method 1011, Cond. A
Vibration	Per MIL-STD-883, Method 2007, Cond. A
Hermetic Seal	Leak rate less than 1×10^{-8} atm.cc/s of helium, crystal only.
Soldering conditions	See MAX reflow profile below; The device may be reflowed once. Reflowing upside down is not allowed. NO CLEAN assembly is recommended.

Note: For lower frequencies, please refer to NEL AB series of VCXO

MAX Reflow Profile



The device may be reflowed once. Reflowing upside down is not allowed. NO CLEAN assembly is recommended.

